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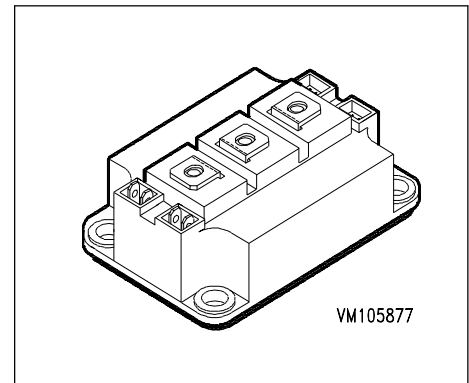
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



IGBT Power Module

- Half-bridge
- Including fast free-wheeling diodes
- Package with insulated metal base plate
- $R_{G\ on, \min} = 15\ \Omega$



| Type | V_{CE} | I_C | Package | Ordering Code |
|--------------------|----------|-------|---------------|------------------|
| BSM 100 GB 170 DN2 | 1700V | 145A | HALF-BRIDGE 2 | C67070-A2703-A67 |

Maximum Ratings

| Parameter | Symbol | Values | Unit |
|---|-------------|---------------|------------|
| Collector-emitter voltage | V_{CE} | 1700 | V |
| Collector-gate voltage | V_{CGR} | 1700 | |
| $R_{GE} = 20\ k\Omega$ | | | |
| Gate-emitter voltage | V_{GE} | ± 20 | |
| DC collector current | I_C | | A |
| $T_C = 25\ ^\circ C$ | | 145 | |
| $T_C = 80\ ^\circ C$ | | 100 | |
| Pulsed collector current, $t_p = 1\ ms$ | I_{Cpuls} | | |
| $T_C = 25\ ^\circ C$ | | 290 | |
| $T_C = 80\ ^\circ C$ | | 200 | |
| Power dissipation per IGBT | P_{tot} | | W |
| $T_C = 25\ ^\circ C$ | | 1000 | |
| Chip temperature | T_j | + 150 | $^\circ C$ |
| Storage temperature | T_{stg} | -40 ... + 125 | |
| Thermal resistance, chip case | R_{thJC} | ≤ 0.13 | K/W |
| Diode thermal resistance, chip case | R_{thJCD} | ≤ 0.4 | |
| Insulation test voltage, $t = 1\ min.$ | V_{is} | 4000 | Vac |
| Creepage distance | - | 20 | mm |
| Clearance | - | 11 | |
| DIN humidity category, DIN 40 040 | - | F | sec |
| IEC climatic category, DIN IEC 68-1 | - | 40 / 125 / 56 | |

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

Static Characteristics

| | | | | | |
|--|---------------|--------|------------|------------|----|
| Gate threshold voltage $V_{GE} = V_{CE}, I_C = 8\text{ mA}$ | $V_{GE(th)}$ | 4.8 | 5.5 | 6.2 | V |
| Collector-emitter saturation voltage $V_{GE} = 15\text{ V}, I_C = 100\text{ A}, T_j = 25\text{ °C}$ $V_{GE} = 15\text{ V}, I_C = 100\text{ A}, T_j = 125\text{ °C}$ | $V_{CE(sat)}$ | - - | 3.4 4.5 | 3.9 5.3 | |
| Zero gate voltage collector current $V_{CE} = 1700\text{ V}, V_{GE} = 0\text{ V}, T_j = 25\text{ °C}$ $V_{CE} = 1700\text{ V}, V_{GE} = 0\text{ V}, T_j = 125\text{ °C}$ | I_{CES} | - - | 0.8 3.2 | 1 - | mA |
| Gate-emitter leakage current $V_{GE} = 20\text{ V}, V_{CE} = 0\text{ V}$ | I_{GES} | - | - | 320 | nA |

AC Characteristics

| | | | | | |
|---|-----------|----|-----|---|----|
| Transconductance $V_{CE} = 20\text{ V}, I_C = 100\text{ A}$ | g_{fs} | 36 | - | - | S |
| Input capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$ | C_{iss} | - | 16 | - | nF |
| Output capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$ | C_{oss} | - | 1.3 | - | |
| Reverse transfer capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$ | C_{rss} | - | 0.5 | - | |

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

Switching Characteristics, Inductive Load at $T_j = 125\text{ °C}$

| | | | | | |
|---|--------------|---|-----|------|----|
| Turn-on delay time $V_{CC} = 1200\text{ V}$, $V_{GE} = 15\text{ V}$, $I_C = 100\text{ A}$ $R_{Gon} = 15\ \Omega$ | $t_{d(on)}$ | - | 450 | 900 | ns |
| Rise time $V_{CC} = 1200\text{ V}$, $V_{GE} = 15\text{ V}$, $I_C = 100\text{ A}$ $R_{Gon} = 15\ \Omega$ | t_r | - | 200 | 400 | |
| Turn-off delay time $V_{CC} = 1200\text{ V}$, $V_{GE} = -15\text{ V}$, $I_C = 100\text{ A}$ $R_{Goff} = 15\ \Omega$ | $t_{d(off)}$ | - | 850 | 1200 | |
| Fall time $V_{CC} = 1200\text{ V}$, $V_{GE} = -15\text{ V}$, $I_C = 100\text{ A}$ $R_{Goff} = 15\ \Omega$ | t_f | - | 110 | 160 | |

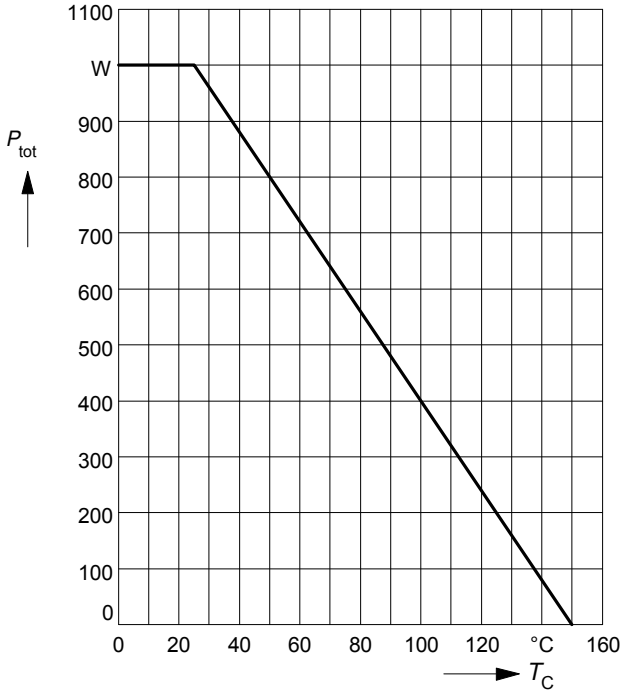
Free-Wheel Diode

| | | | | | |
|---|----------|---|------------|----------|---------------|
| Diode forward voltage $I_F = 100\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 25\text{ °C}$ $I_F = 100\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$ | V_F | - | 2.3 2.1 | 2.8 - | V |
| Reverse recovery time $I_F = 100\text{ A}$, $V_R = -1200\text{ V}$, $V_{GE} = 0\text{ V}$ $di_F/dt = -1000\text{ A}/\mu\text{s}$, $T_j = 125\text{ °C}$ | t_{rr} | - | 0.5 | - | |
| Reverse recovery charge $I_F = 100\text{ A}$, $V_R = -1200\text{ V}$, $V_{GE} = 0\text{ V}$ $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$ | Q_{rr} | - | 8 25 | - - | μC |

Power dissipation

$P_{tot} = f(T_C)$

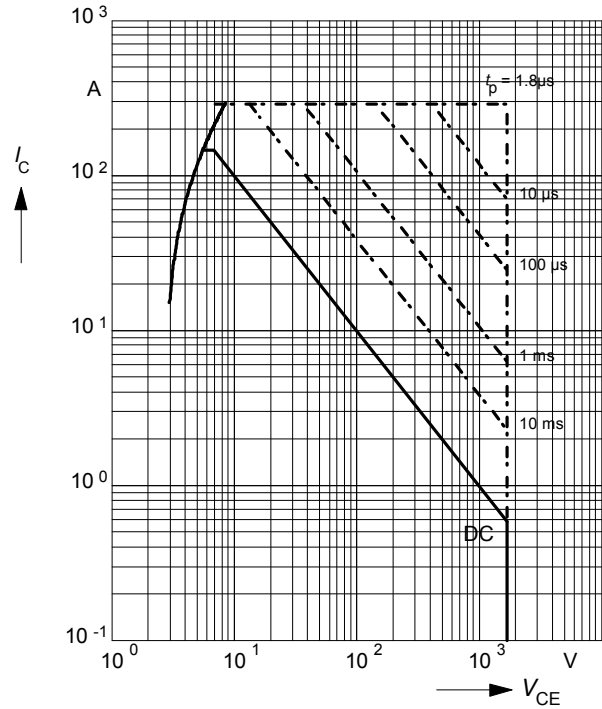
parameter: $T_j \leq 150\text{ }^\circ\text{C}$



Safe operating area

$I_C = f(V_{CE})$

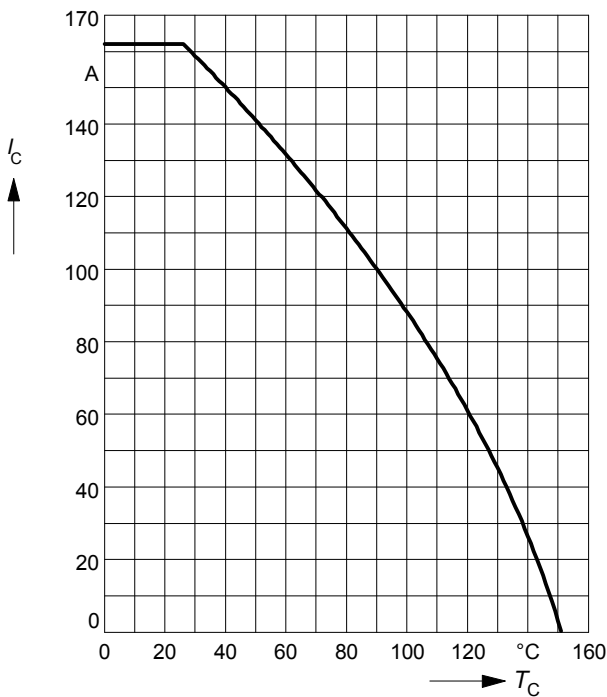
parameter: $D = 0, T_C = 25\text{ }^\circ\text{C}, T_j \leq 150\text{ }^\circ\text{C}$



Collector current

$I_C = f(T_C)$

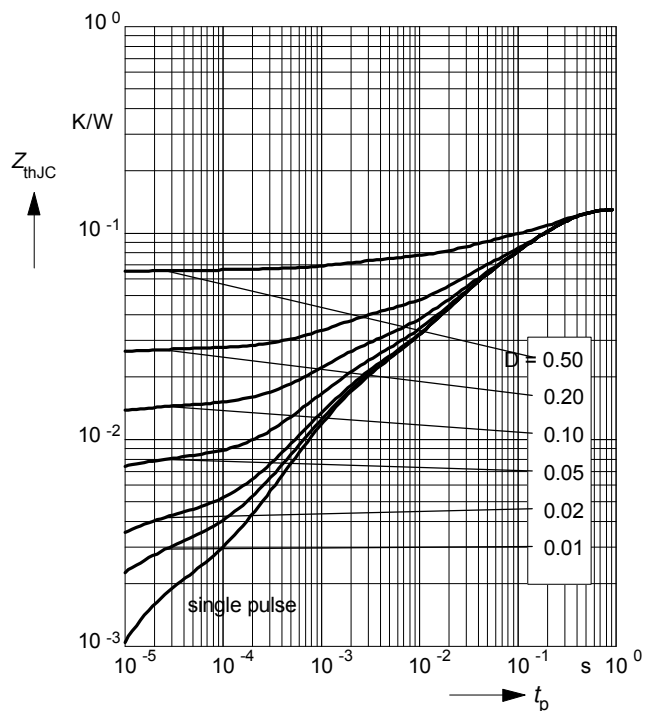
parameter: $V_{GE} \geq 15\text{ V}, T_j \leq 150\text{ }^\circ\text{C}$



Transient thermal impedance IGBT

$Z_{thJC} = f(t_p)$

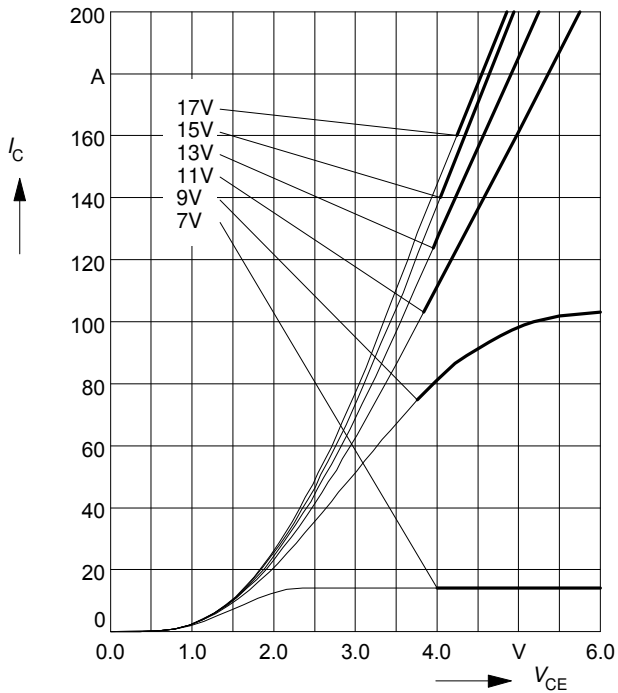
parameter: $D = t_p / T$



Typ. output characteristics

$I_C = f(V_{CE})$

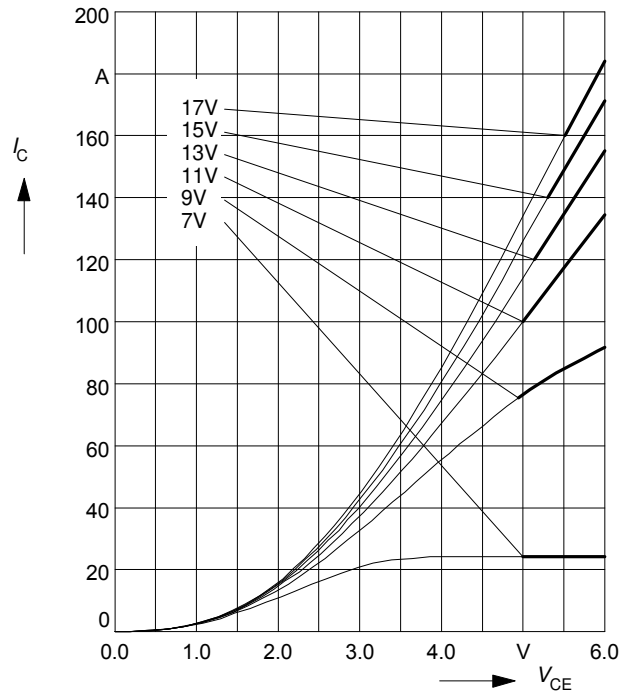
parameter: $t_p = 80 \mu s, T_j = 25 \text{ }^\circ\text{C}$



Typ. output characteristics

$I_C = f(V_{CE})$

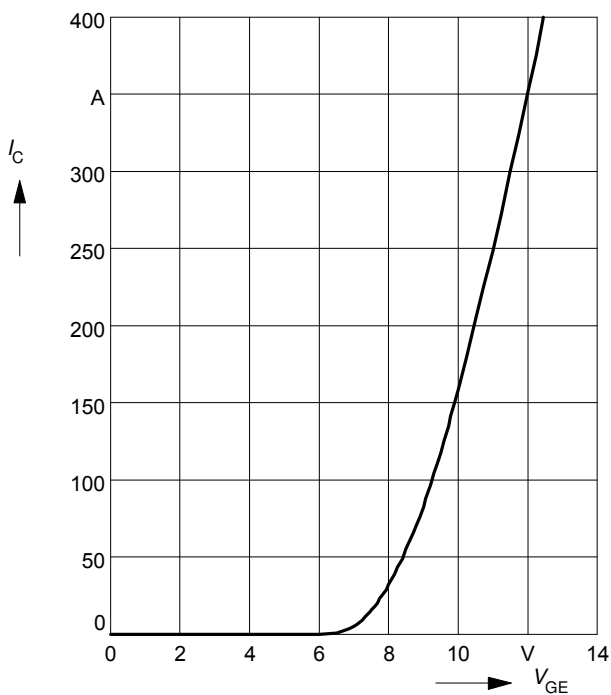
parameter: $t_p = 80 \mu s, T_j = 125 \text{ }^\circ\text{C}$



Typ. transfer characteristics

$I_C = f(V_{GE})$

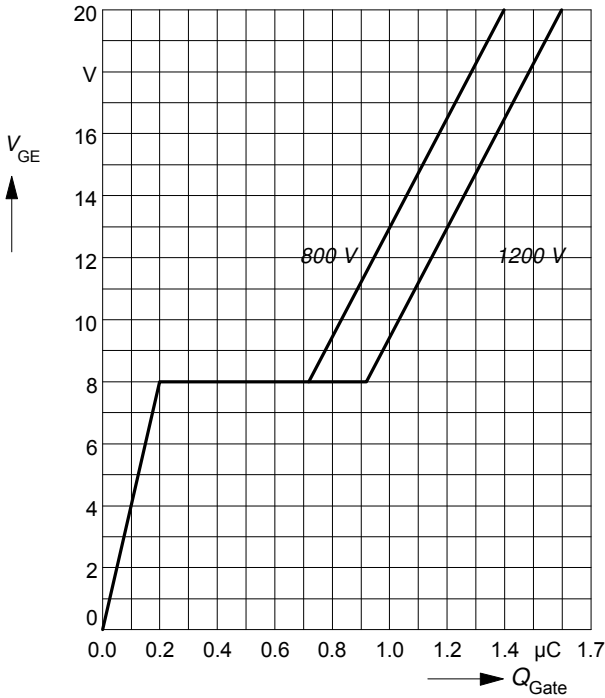
parameter: $t_p = 80 \mu s, V_{CE} = 20 \text{ V}$



Typ. gate charge

$V_{GE} = f(Q_{Gate})$

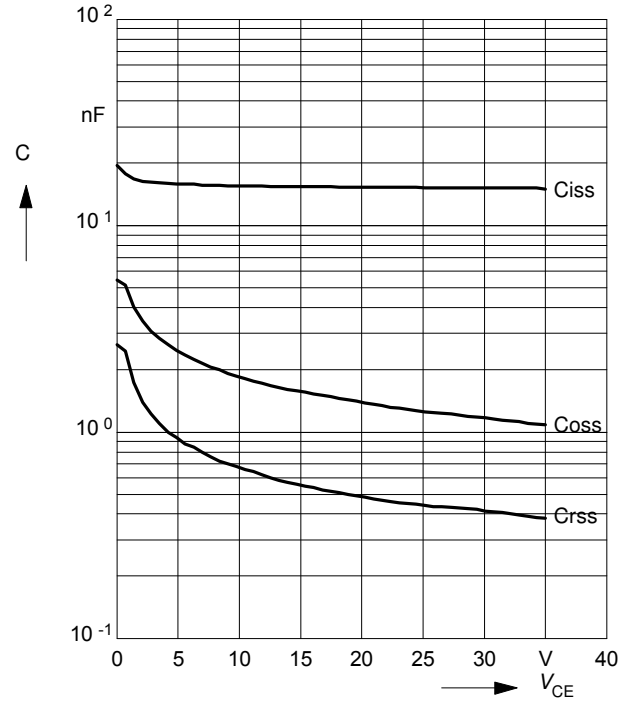
parameter: $I_{C\ puls} = 100\text{ A}$



Typ. capacitances

$C = f(V_{CE})$

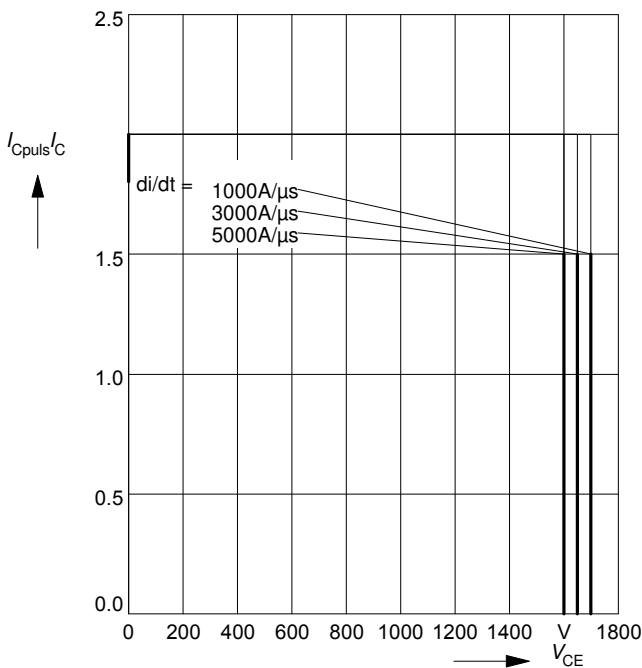
parameter: $V_{GE} = 0, f = 1\text{ MHz}$



Reverse biased safe operating area

$I_{C\ puls} = f(V_{CE}), T_j = 150^\circ\text{C}$

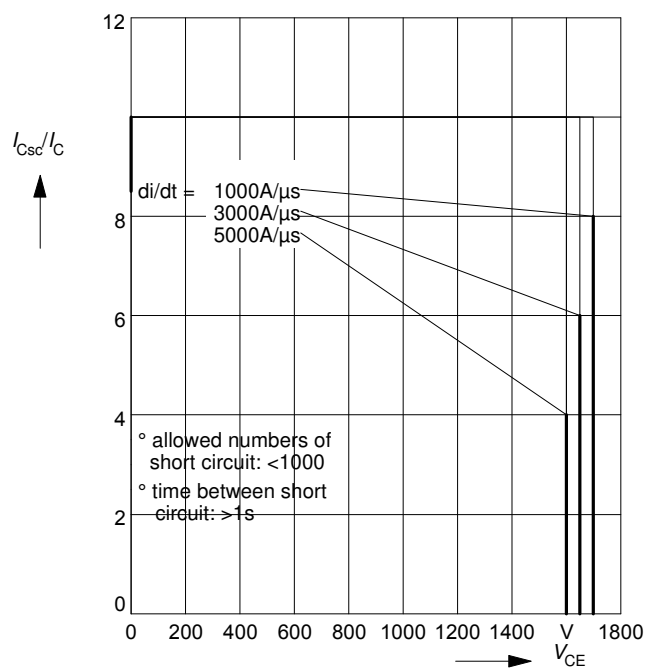
parameter: $V_{GE} = \pm 15\text{ V}, t_p \leq 1\text{ ms}, L < 25\text{ nH}$



Short circuit safe operating area

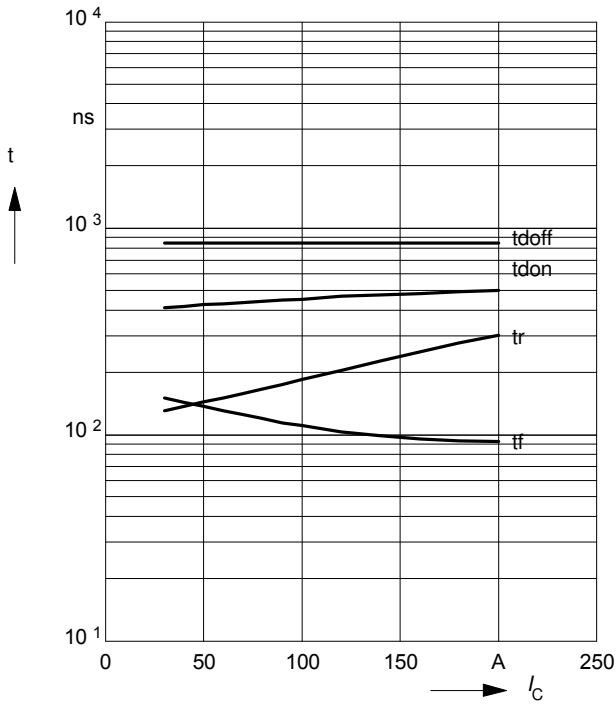
$I_{C\ sc} = f(V_{CE}), T_j = 150^\circ\text{C}$

parameter: $V_{GE} = \pm 15\text{ V}, t_p \leq 10\ \mu\text{s}, L < 25\text{ nH}$



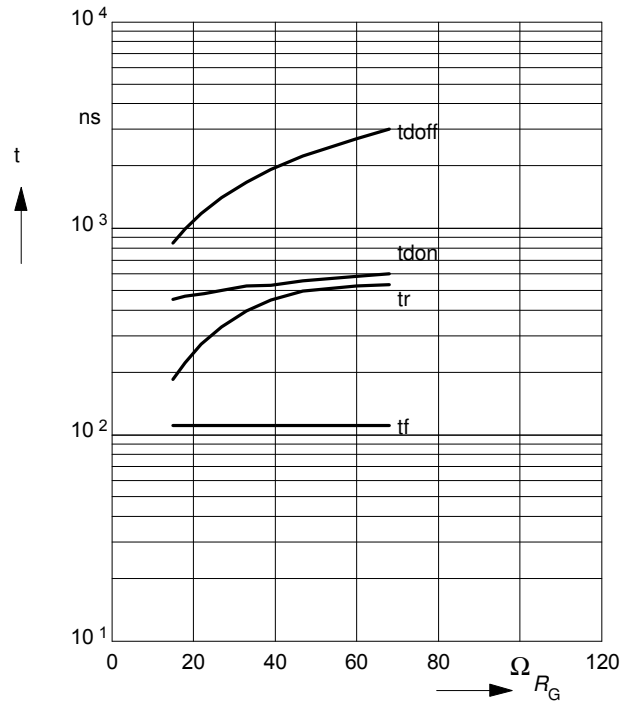
Typ. switching time

$t = f(I_C)$, inductive load, $T_j = 125^\circ\text{C}$
 par.: $V_{CE} = 1200\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $R_G = 15\ \Omega$



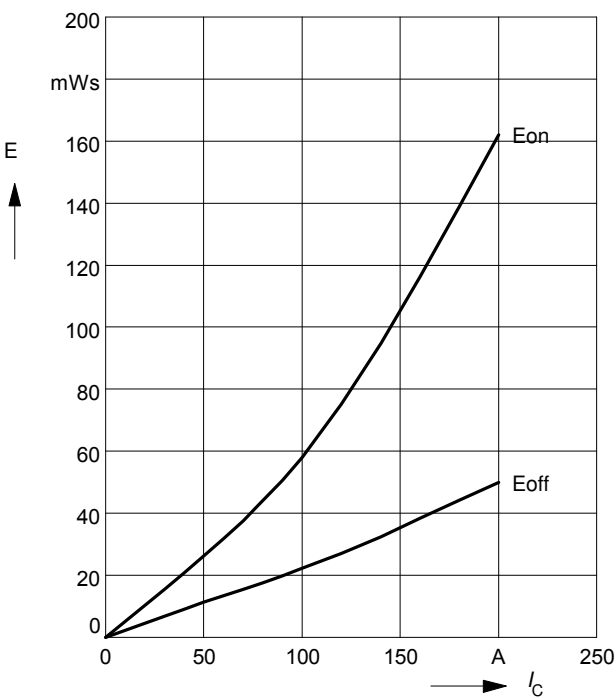
Typ. switching time

$t = f(R_G)$, inductive load, $T_j = 125^\circ\text{C}$
 par.: $V_{CE} = 1200\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $I_C = 100\text{ A}$



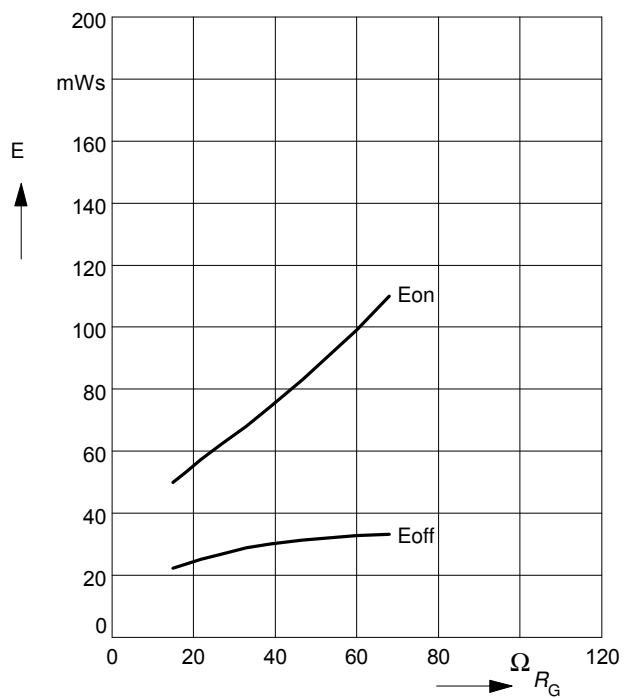
Typ. switching losses

$E = f(I_C)$, inductive load, $T_j = 125^\circ\text{C}$
 par.: $V_{CE} = 1200\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $R_G = 15\ \Omega$



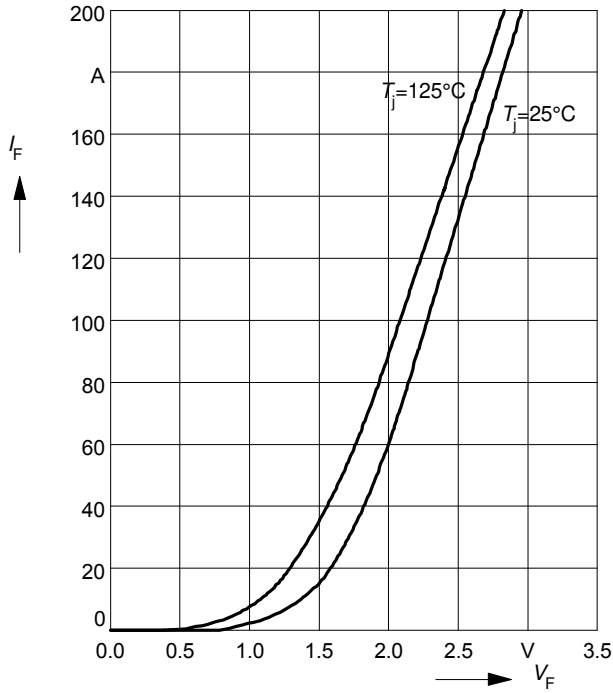
Typ. switching losses

$E = f(R_G)$, inductive load, $T_j = 125^\circ\text{C}$
 par.: $V_{CE} = 1200\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $I_C = 100\text{ A}$



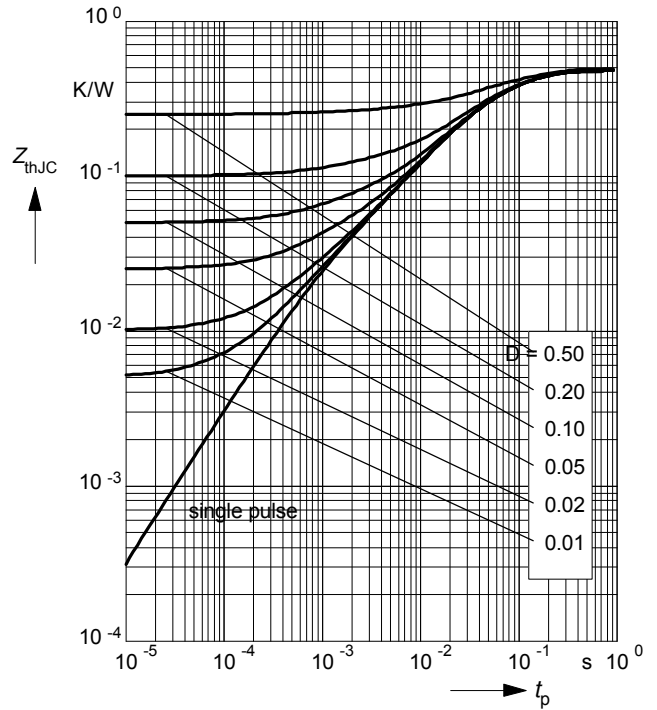
Forward characteristics of fast recovery reverse diode $I_F = f(V_F)$

parameter: T_j

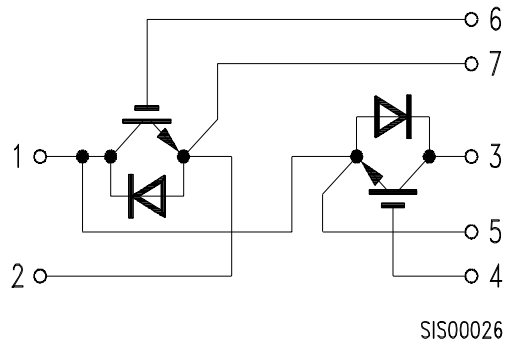


Transient thermal impedance Diode $Z_{thJC} = f(t_p)$

parameter: $D = t_p / T$



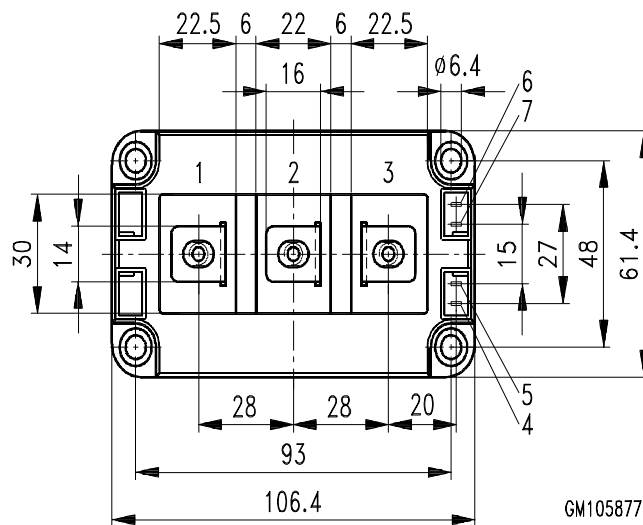
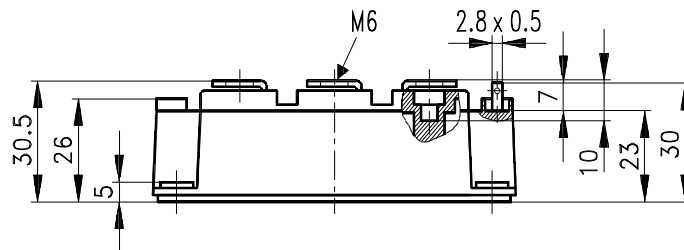
Circuit Diagram



Package Outlines

Dimensions in mm

Weight: 420 g



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